NSN 5961-01-465-3150

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-465-3150 **Inclosure Material:** Glass **Overall Length:** 10.15 millimeters **Overall Height:** 0.80 millimeters **Overall Width:** 10.15 millimeters **Internal Configuration:** Junction contact **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 collector to base voltage/static/emitter open and 10.0 collector to emitter voltage/static/base open and 1.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 65.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 580.0 milliwatts small-signal input power, common-emitter outside diameter **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 150.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No